Magnetism

in diluted magnetic oxides

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Layout



- \checkmark Magnetism in ZrO₂ and in rutile TiO₂
- Cation vacancies and substitution of cation by alkalic metal atom
- Density functional calculations for oxide compounds
- Magnetic moments on O atoms

Conclusions

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Magnetism in oxide compounds

Nonmagnetic oxides + a nonmagnetic impurity element

In diluted magnetic semiconductors magnetic dopants introduce magnetism in the mixed system.

In some oxide compounds specific nonmagnetic host doping can induce local magnetic moments on neighbor atoms. Making them ferromagnetic can open the possible application in the field of spintronics.

 \Rightarrow Prototype: vacancy-induced ferromagnetism in **ZrO** $_2$

New types of devices: the electric field changes the charge and the spin of electrons

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Motivation

Vacancy-induced d^0 ferromagnetism in oxide compounds [1]. Model Hamiltonian with effective parameters (U, W, V, t, n_h) + Heisenberg model for magnetic exchange coupling analysis.



Left: Magnetic couplings (in Kelvin) as a function of separation of vacancies, in units of the cubic lattice spacing. Right: Curie temperature as a function of the potential V (in units of W).

[1] G. Bouzerar and T. Ziman, PRL 96 (2006) 207602.

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Magnetism without magnetic ions

Questions to be answered:

- Does the stable charge state of the isolated defect carry a magnetic moment?
- What is the range of magnetic exchange interactions between a pair of defects in stable charge states?
- What is the minimum concentration of defects which will establish a continuous percolation in the lattice?
- Can be a minimum defect concentration needed for magnetic percolation granted thermodynamically?
 ?? Formation energy of the defect ??

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It is difficult to control the concentration of vacancies in oxide in the vacancy-induced d⁰ ferromagnetism in oxide compounds.

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- It is difficult to control the concentration of vacancies in oxide in the vacancy-induced d⁰ ferromagnetism in oxide compounds.
- The vacancy on oxygen site is the natural defect in many oxides.
 A cation vacancy is a very strong defect with high formation energy.

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- The vacancy on oxygen site is the natural defect in many oxides.
 A cation vacancy is a very strong defect with high formation energy.
- Alkalic metal atom substituting the cation can also create magnetism in oxide. The concentration of alkalic metal dopants can be well controlled.

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What alkalic metal impurities create the magnetism in the ZrO_2 and in the rutile TiO_2 ?

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Theoretical tools

- Real-space spin-density-functional method => reliable ground-state total energy and charge- and spin-densities.
- Implementation: full-potential linearized augmented plane wave method (FP LAPW, WIEN2k package).
- ✓ impurity incorporated into the ZrO₂ or into the rutile TiO₂ supercells containing 24, 48, and 96 atoms with either cubic or tetragonal symmetry.



 \implies limit of single impurity in host.

Implementation: TB-LMTO

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The cubic supercell NaZr₇O₁₆, a = 5.256 Å. There are two types of oxygens: the Na neighbors and others. No relaxation of geometry is included. The local magnetic moments are obtained by integration over the muffin-tin sphere ($R_{Zr} = R_{imp} = 2.35$ a.u., $R_O = 1.70$ a.u.). The unit cell including 24 atoms has magnetic moment $\mu_{cell} = 2.42 \ \mu_B$.

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*Impurity in ZrO*₂



47/48 atoms in the unit cell - 6.25%

| Impurity | $\mu_{\mathbf{imp}}$ | $\mu_{\mathbf{O_1}}$ | $\mu_{\mathbf{O_2}}$ | $\mu_{\mathbf{Zr_1}}$ | $\mu_{\mathbf{cell}}$ |
|----------|----------------------|----------------------|----------------------|-----------------------|-----------------------|
| vac | - | 0.41 | 0.05 | -0.02 | 4.00 |
| Na | 0.00 | 0.17 | 0.03 | 0.00 | 1.70 |
| K | 0.07 | 0.25 | 0.05 | -0.01 | 2.81 |
| Rb | 0.37 | 0.25 | 0.02 | 0.00 | 3.00 |
| Cs | 0.66 | 0.19 | 0.02 | 0.01 | 3.00 |

95/96 atoms in the unit cell - 3.125%

| vac | - | 0.41 | 0.03 | 0.00 | 4.00 |
|-----|------|------|------|-------|------|
| Na | 0.00 | 0.12 | 0.01 | 0.00 | 1.30 |
| K | 0.07 | 0.22 | 0.03 | -0.01 | 2.63 |
| Rb | 0.37 | 0.25 | 0.02 | 0.00 | 3.00 |
| Cs | 0.65 | 0.19 | 0.01 | 0.01 | 3.00 |

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Impurity in TiO₂



23/24 atoms in the unit cell - 12.5%

| Impurity | $\mu_{\mathbf{imp}}$ | $\mu_{\mathbf{O_1}}$ | $\mu_{\mathbf{O_2}}$ | $\mu_{\mathbf{Ti_1}}$ | $\mu_{\mathbf{cell}}$ |
|----------|----------------------|----------------------|----------------------|-----------------------|-----------------------|
| vac | - | 0.51 | 0.42 | -0.08 | 3.94 |
| Na | 0.02 | 0.32 | 0.25 | -0.05 | 2.58 |
| K | 0.21 | 0.28 | -0.05 | -0.01 | 1.60 |
| Rb | 0.27 | 0.17 | 0.03 | 0.02 | 1.30 |
| Cs | 0.16 | 0.06 | 0.01 | 0.04 | 0.70 |

96 atoms in the unit cell - 3.125%

| Na | 0.00 | 0.09 | 0.05 | -0.01 | 0.83 |
|----|------|------|------|-------|------|
| K | 0.36 | 0.31 | 0.19 | 0.01 | 2.92 |
| Rb | 0.58 | 0.27 | 0.23 | 0.04 | 3.00 |
| Cs | 0.23 | 0.09 | 0.05 | 0.07 | 1.50 |

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LDOS for TiO_2



Spin resolved LDOS for the rutile supercell Ti_2O_4 : total DOS, then LDOS for Ti

and O are presented.

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LDOS for KTi_7O_{16}



Spin resolved LDOS for the rutile supercell KTi_7O_{16} : up (left panel) and down

(right panel), first raw is total DOS, then LDOS for O is presented.

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|----|-------|-----|-------|---|------|
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*Magnetization for KZr*₇O₁₆



Local magnetization for the KZr_7O_{16} in the plane (110).

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*Formation energies in anastase TiO*₂



Defect formation energies as a function of Fermi level for anastase.

$\Delta H(D^q, E_F, \mu) = [E(D^q) - E(H)] + (\mu_\alpha^{elem} + \Delta \mu_\alpha) + q(E_v + \Delta E_F)$

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Conclusions

The substitution of Zr(Ti) by Na, K, Rb and Cs creates magnetic moments localized on neighboring oxygen atoms in ZrO₂ (TiO₂).

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- The substitution of Zr(Ti) by Na, K, Rb and Cs creates magnetic moments localized on neighboring oxygen atoms in ZrO₂ (TiO₂).
- This is associated with the development of an impurity band in the vicinity of Fermi level. The impurity band is splitted, majority band is occupied and minority band unoccupied.

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Conclusions

- The substitution of Zr(Ti) by Na, K, Rb and Cs creates magnetic moments localized on neighboring oxygen atoms in ZrO₂ (TiO₂).
- This is associated with the development of an impurity band in the vicinity of Fermi level. The impurity band is splitted, majority band is occupied and minority band unoccupied.
- Our preliminary calculations of formation energies for creation of a cation vacancy as well as for substitution of cation by an alkalic metal atom in rutile TiO₂ indicate defect concentrations far to achieve magnetic percolation.

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